IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In Re the Application of:

    DAE-YOUNG KIM

Application No.:

Filed:

For: **method of manufacturing semiconductor device**

Art Group:

Examiner:

INFORMATION DISCLOSURE STATEMENT UNDER 37 C.F.R. §1.97

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

In accordance with the duty of disclosure, enclosed is a copy of Information Disclosure Statement by Applicant (form PTO/SB/08), which is being submitted concurrently with the Utility Application. It is respectfully requested that the cited references be considered and that the enclosed copy of PTO/SB/08 be initialed by the Examiner to indicate such consideration and a copy thereof returned to applicant(s). Copies of the references cited on PTO/SB/08 are enclosed herewith.
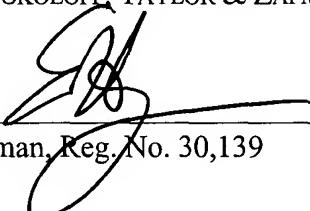
The submission of this Information Disclosure Statement is not to be construed as a representation that a search has been made in the subject application and is not to be construed as an admission that the information cited in this statement is material to patentability.

Please charge any fees due to Deposit Account 02-2666. A duplicate copy of the Fee Transmittal (PTO/SB/17) is enclosed for this purpose.

Respectfully submitted,

BLAKELY, SOKOLOFF, TAYLOR & ZAFMAN LLP

Date: _____

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51876P356

INFORMATION DISCLOSURE
STATEMENT BY APPLICANT
(use as many sheets as necessary)

				Complete if Known	
Sheet	1	**of**	2	Application Number	
				Filing Date	
				First Named Inventor	Dae-Young Kim
				Art Unit	
				Examiner Name	
				Attorney Docket Number	51876P356

U.S. PATENT DOCUMENTS

Examiner Initials*	Cite No.[1]	Document Number — Number – Kind Code[2] (if known)	Publication Date or Issue Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		US-6525965	02-25-2003	Ghodsi	
		US-6466489	10-15-2002	Ieong et al.	
		US-6355954	03-12-2002	Gall et al.	
		US-6238967	05-29-2001	Shiho et al.	
		US-6211011	04-03-2001	Chen	
		US-6030871	02-29-2000	Eitan	
		US-6025224	02-15-2000	Gall et al.	
		US-5216265	06-01-1993	Anderson et al.	
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FOREIGN PATENT DOCUMENTS

Examiner Initials*	Cite No.[1]	Foreign Patent Document — Country Code[3] - Number[4] - Kind Code[5] (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T[6]
		10-303140	11-13-1998	St. Microelectron SRL		
		09-97898	04-08-1997	Sanyo Electric Co Ltd		

Examiner Signature		Date Considered	

Substitute for form 1449A/PTO				Complete if Known	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT *(use as many sheets as necessary)*				Application Number	
				Filing Date	
				First Named Inventor	Dae-Young Kim
				Art Unit	
				Examiner Name	
Sheet	2	**of**	2	Attorney Docket Number	51876P356

OTHER ART - NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No.[1]	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T[2]

Examiner Signature		Date Considered	

*Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication.

[1]Applicant's unique citation designation number. [2]Applicant is to place a check mark here if English language Translation is attached.

Based on PTO/SB/08B (05-03) as modified by Blakely, Solokoff, Taylor & Zafman (wlr) 05/02/2003.
Send To: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450

Information Disclosure Statement

New U.S. Patent Application for
METHOD OF MANUFACTURING SEMICONDUCTOR DEVICE
Our Ref. No.: P03H1054/US/yh

Reference No.:

(1) US Patent No. 6,525,965
(2) US Patent No. 6,466,489
(3) US Patent No. 6,355,954
(4) US Patent No. 6,238,967
(5) US Patent No. 6,211,011
(6) US Patent No. 6,030,871
(7) US Patent No. 6,025,224
(8) US Patent No. 5,216,265
(9) JP Laid-Open No. 10-303140
(10) JP Laid-Open No. 09-97898